

isc Silicon NPN Power Transistor

DESCRIPTION

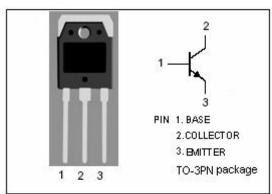
- · High Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 500V(Min)
- · High Switching Speed
- · Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

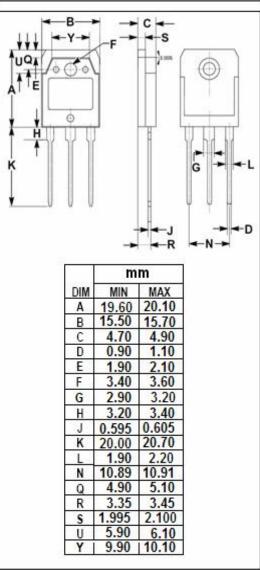
APPLICATIONS

 Designed for switching regulator and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{СВО}	Collector-Base Voltage	800	V
V _{CEO}	Collector-Emitter Voltage	500	V
V _{EBO}	Emitter-Base voltage	7	٧
lc	Collector Current-Continuous	10	Α
Ісм	Collector Current-Peak	20	Α
I _B	Base Current-Continuous	3	Α
Pc	Collector Power Dissipation @ T _C =25℃	90	W
TJ	Junction Temperature 150		$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$







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2SC3450

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	800			V		
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA; R _{BE} = ∞	500			V		
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1m A; I _C = 0	7			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 4A; I _B = 0.8A			1.0	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 4A; I _B = 0.8A			1.5	V		
Ісво	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			10	μА		
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	μ А		
h _{FE-1}	DC Current Gain	I _C = 0.8A; V _{CE} = 5V	15		50			
h _{FE-2}	DC Current Gain	I _C = 4A; V _{CE} = 5V	8					
f _T	Current-Gain—Bandwidth Product	I _C = 0.8A; V _{CE} = 10V		18		MHz		
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		120		pF		
Switching Times								
ton	Turn-on Time				0.5	μ S		
t _{stg}	Storage Time	I _C = 5A, I _{B1} = 1A; I _{B2} = -2A R _L = 40 Ω; V _{CC} = 200V			3.0	μS		
t _f	Fall Time				0.3	μS		

♦ h_{FE-1} Classifications

L	М	N
15-30	20-40	30-50

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